

February 1988

**MM54C00/MM74C00, MM54C02/MM74C02, MM54C04/MM74C04,  
MM54C10/MM74C10, MM54C20/MM74C20**

## MM54C00/MM74C00 Quad 2-Input NAND Gate MM54C02/MM74C02 Quad 2-Input NOR Gate MM54C04/MM74C04 Hex Inverter MM54C10/MM74C10 Triple 3-Input NAND Gate MM54C20/MM74C20 Dual 4-Input NAND Gate

### General Description

These logic gates employ complementary MOS (CMOS) to achieve wide power supply operating range, low power consumption, high noise immunity and symmetric controlled rise and fall times. With features such as this the 54C/74C logic family is close to ideal for use in digital systems. Function and pin out compatibility with series 54/74 devices minimizes design time for those designers already familiar with the standard 54/74 logic family.

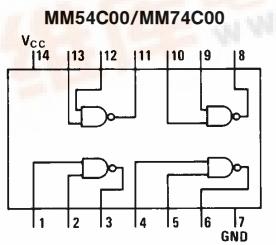
All inputs are protected from damage due to static discharge by diode clamps to V<sub>CC</sub> and GND.

### Features

- Wide supply voltage range 3V to 15V
- Guaranteed noise margin 1V
- High noise immunity 0.45 V<sub>CC</sub> (typ.)
- Low power consumption 10 nW/package (typ.)
- Low power Fan out of 2 driving 74L
- TTL compatibility

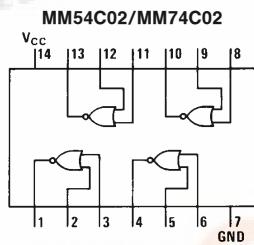
### Connection Diagrams

#### Dual-In-Line Packages



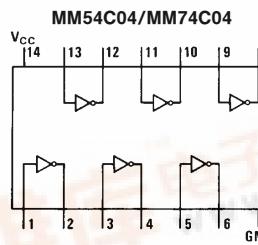
Top View

Order Number MM54C00 or  
MM74C00



Top View

Order Number MM54C02 or  
MM74C02

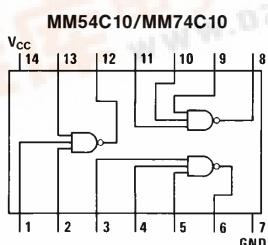


Top View

Order Number MM54C04 or  
MM74C04

Top View

Order Number MM54C00 or  
MM74C00

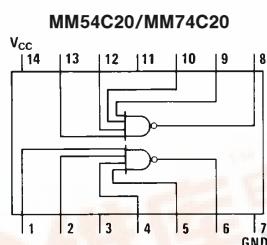


Top View

Order Number MM54C10 or  
MM74C10

Top View

Order Number MM54C20 or  
MM74C20



Top View

## Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Voltage at Any Pin	-0.3V to V <sub>CC</sub> + 0.3V	Operating V <sub>CC</sub> Range	3.0V to 15V
Operating Temperature Range		Maximum V <sub>CC</sub> Voltage	18V
54C	-55°C to +125°C	Power Dissipation (P <sub>D</sub> )	
74C	-40°C to +85°C	Dual-In-Line	700 mW
Storage Temperature Range	-65°C to +150°C	Small Outline	500 mW
		Lead Temperature (Soldering, 10 seconds)	300°C

## DC Electrical Characteristics

Min/Max limits apply across the guaranteed temperature range unless otherwise noted

Symbol	Parameter	Conditions	Min	Typ	Max	Units
<b>CMOS TO CMOS</b>						
V <sub>IN(1)</sub>	Logical "1" Input Voltage	V <sub>CC</sub> = 5.0V	3.5			V
		V <sub>CC</sub> = 10V	8.0			V
V <sub>IN(0)</sub>	Logical "0" Input Voltage	V <sub>CC</sub> = 5.0V			1.5	V
		V <sub>CC</sub> = 10V			2.0	V
V <sub>OUT(1)</sub>	Logical "1" Output Voltage	V <sub>CC</sub> = 5.0V, I <sub>O</sub> = -10 μA	4.5			V
		V <sub>CC</sub> = 10V, I <sub>O</sub> = -10 μA	9.0			V
V <sub>OUT(0)</sub>	Logical "0" Output Voltage	V <sub>CC</sub> = 5.0V, I <sub>O</sub> = 10 μA			0.5	V
		V <sub>CC</sub> = 10V, I <sub>O</sub> = 10 μA			1.0	V
I <sub>IN(1)</sub>	Logical "1" Input Current	V <sub>CC</sub> = 15V, V <sub>IN</sub> = 15V		0.005	1.0	μA
I <sub>IN(0)</sub>	Logical "0" Input Current	V <sub>CC</sub> = 15V, V <sub>IN</sub> = 0V	-1.0	-0.005		μA
I <sub>CC</sub>	Supply Current	V <sub>CC</sub> = 15V		0.01	15	μA
<b>LOW POWER TO CMOS</b>						
V <sub>IN(1)</sub>	Logical "1" Input Voltage	54C, V <sub>CC</sub> = 4.5V	V <sub>CC</sub> - 1.5			V
		74C, V <sub>CC</sub> = 4.75V	V <sub>CC</sub> - 1.5			V
V <sub>IN(0)</sub>	Logical "0" Input Voltage	54C, V <sub>CC</sub> = 4.5V			0.8	V
		74C, V <sub>CC</sub> = 4.75V			0.8	V
V <sub>OUT(1)</sub>	Logical "1" Output Voltage	54C, V <sub>CC</sub> = 4.5V, I <sub>O</sub> = -10 μA	4.4			V
		74C, V <sub>CC</sub> = 4.75V, I <sub>O</sub> = -10 μA	4.4			V
V <sub>OUT(0)</sub>	Logical "0" Output Voltage	54C, V <sub>CC</sub> = 4.5V, I <sub>O</sub> = 10 μA			0.4	V
		74C, V <sub>CC</sub> = 4.75V, I <sub>O</sub> = 10 μA			0.4	V
<b>CMOS TO LOW POWER</b>						
V <sub>IN(1)</sub>	Logical "1" Input Voltage	54C, V <sub>CC</sub> = 4.5V	4.0			V
		74C, V <sub>CC</sub> = 4.75V	4.0			V
V <sub>IN(0)</sub>	Logical "0" Input Voltage	54C, V <sub>CC</sub> = 4.5V			1.0	V
		74C, V <sub>CC</sub> = 4.75V			1.0	V
V <sub>OUT(1)</sub>	Logical "1" Output Voltage	54C, V <sub>CC</sub> = 4.5V, I <sub>O</sub> = -360 μA	2.4			V
		74C, V <sub>CC</sub> = 4.75V, I <sub>O</sub> = -360 μA	2.4			V
V <sub>OUT(0)</sub>	Logical "0" Output Voltage	54C, V <sub>CC</sub> = 4.5V, I <sub>O</sub> = 360 μA			0.4	V
		74C, V <sub>CC</sub> = 4.75V, I <sub>O</sub> = 360 μA			0.4	V
<b>OUTPUT DRIVE (see 54C/74C Family Characteristics Data Sheet) T<sub>A</sub> = 25°C (short circuit current)</b>						
I <sub>SOURCE</sub>	Output Source Current	V <sub>CC</sub> = 5.0V, V <sub>IN(0)</sub> = 0V, V <sub>OUT</sub> = 0V	-1.75			mA
I <sub>SOURCE</sub>	Output Source Current	V <sub>CC</sub> = 10V, V <sub>IN(0)</sub> = 0V, V <sub>OUT</sub> = 0V	-8.0			mA
I <sub>SINK</sub>	Output Sink Current	V <sub>CC</sub> = 5.0V, V <sub>IN(1)</sub> = 5.0V, V <sub>OUT</sub> = V <sub>CC</sub>	1.75			mA
I <sub>SINK</sub>	Output Sink Current	V <sub>CC</sub> = 10V, V <sub>IN(1)</sub> = 10V, V <sub>OUT</sub> = V <sub>CC</sub>	8.0			mA

## AC Electrical Characteristics\* $T_A = 25^\circ\text{C}$ , $C_L = 50 \text{ pF}$ , unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Units
<b>MM54C00/MM74C00, MM54C02/MM74C02, MM54C04/MM74C04</b>						
$t_{pd0}, t_{pd1}$	Propagation Delay Time to Logical "1" or "0"	$V_{CC} = 5.0\text{V}$		50	90	ns
		$V_{CC} = 10\text{V}$		30	60	ns
$C_{IN}$	Input Capacitance	(Note 2)		6.0		pF
$C_{PD}$	Power Dissipation Capacitance	(Note 3) Per Gate or Inverter		12		pF
<b>MM54C10/MM74C10</b>						
$t_{pd0}, t_{pd1}$	Propagation Delay Time to Logical "1" or "0"	$V_{CC} = 5.0\text{V}$		60	100	ns
		$V_{CC} = 10\text{V}$		35	70	ns
$C_{IN}$	Input Capacitance	(Note 2)		7.0		pF
$C_{PD}$	Power Dissipation Capacitance	(Note 3) Per Gate		18		pF
<b>MM54C20/MM74C20</b>						
$t_{pd0}, t_{pd1}$	Propagation Delay Time to Logical "1" or "0"	$V_{CC} = 5.0\text{V}$		70	115	ns
		$V_{CC} = 10\text{V}$		40	80	ns
$C_{IN}$	Input Capacitance	(Note 2)		9		pF
$C_{PD}$	Power Dissipation Capacitance	(Note 3) Per Gate		30		pF

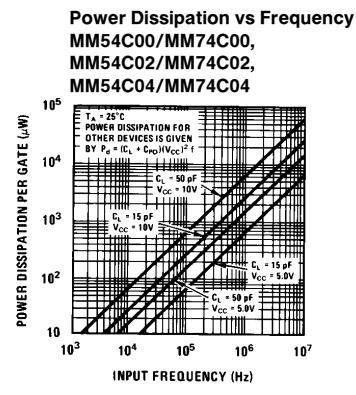
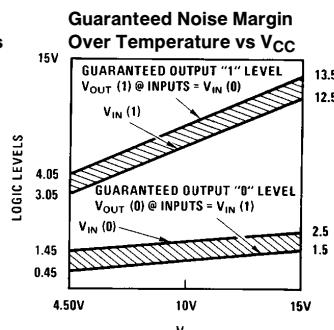
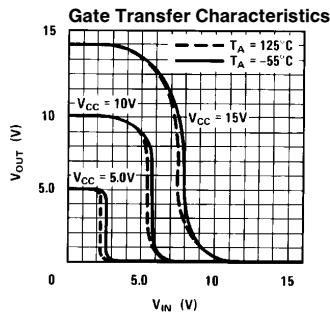
\*AC Parameters are guaranteed by DC correlated testing.

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: Capacitance is guaranteed by periodic testing.

Note 3:  $C_{PD}$  determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics Application Note—AN-90.

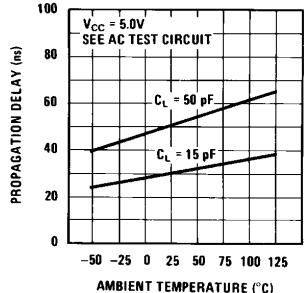
## Typical Performance Characteristics



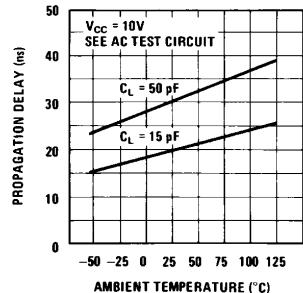
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## Typical Performance Characteristics (Continued)

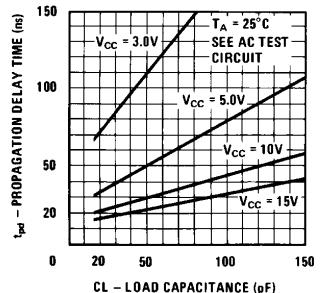
Propagation Delay vs  
Ambient Temperature  
MM54C00/MM74C00,  
MM54C02/MM74C02,  
MM54C04/MM74C04



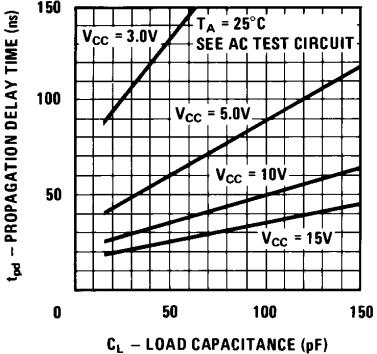
Propagation Delay vs  
Ambient Temperature  
MM54C00/MM74C00,  
MM54C02/MM74C02,  
MM54C04/MM74C04



Propagation Delay Time vs  
Load Capacitance  
MM54C00/MM74C00,  
MM54C02/MM74C02,  
MM54C04/MM74C04

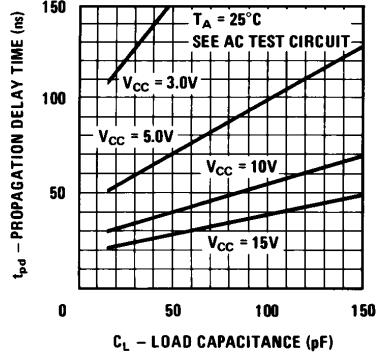


Propagation Delay Time vs  
Load Capacitance  
MM54C10/MM74C10



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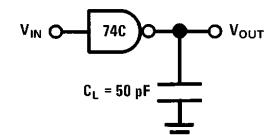
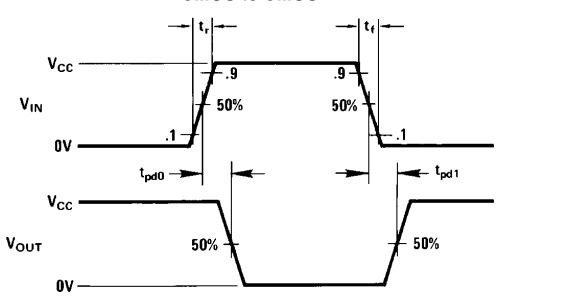
Propagation Delay Time vs  
Load Capacitance  
MM54C20/MM74C20



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## Switching Time Waveforms and AC Test Circuit

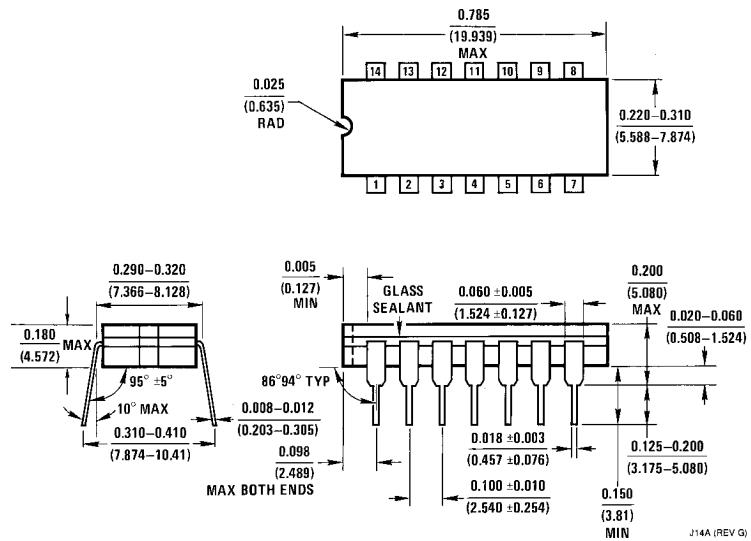
CMOS to CMOS



TL/F/5877-11

Note: Delays measured with input  $t_r, t_f \leq 20$  ns.

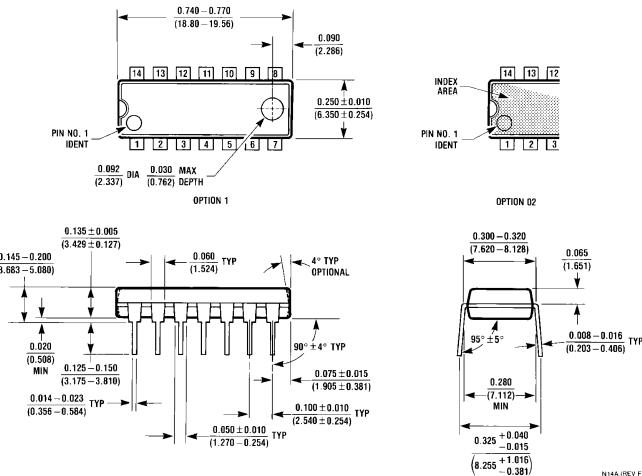
## **Physical Dimensions** inches (millimeters)



**Ceramic Dual-In-Line Package (J)**  
Order Number MM54C00J, MM54C02J, MM54C04J, MM54C10J, MM54C20J,  
MM74C00J, MM74C02J, MM74C04J, MM74C10J or MM74C20J  
NS Package Number J14A

**MM54C00/MM74C00, MM54C02/MM74C02, MM54C04/MM74C04,  
MM54C10/MM74C10, MM54C20/MM74C20**

### Physical Dimensions inches (millimeters) (Continued)



**Molded Dual-In-Line Package (N)**

**Order Number MM54C00N, MM54C02N, MM54C04N, MM54C10N, MM54C20N,  
MM74C00N, MM74C02N, MM74C04N, MM74C10N or MM74C20N  
NS Package Number N14A**

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